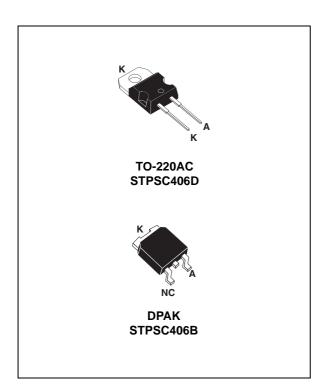


## 600 V power Schottky silicon carbide diode

Datasheet - production data



### **Description**

The SiC diode is an ultrahigh performance power Schottky diode. It is manufactured using a silicon carbide substrate. The wide bandgap material allows the design of a Schottky diode structure with a 600 V rating. Due to the Schottky construction no recovery is shown at turn-off and ringing patterns are negligible. The minimal capacitive turn-off behavior is independent of temperature.

ST SiC diodes will boost the performance of PFC operations in hard switching conditions.

**Table 1. Device summary** 

I <sub>F(AV)</sub>	4 A
$V_{RRM}$	600 V
T <sub>j (max)</sub>	175 °C
Q <sub>C (typ)</sub>	3 nC

#### **Features**

- No or negligible reverse recovery
- Switching behavior independent of temperature
- Dedicated to PFC boost diode

Characteristics STPSC406

### 1 Characteristics

Table 2. Absolute ratings (limiting values at 25 °C unless otherwise specified)

Symbol		Value	Unit	
$V_{RRM}$	Repetitive peak reverse	Repetitive peak reverse voltage		V
I <sub>F(RMS)</sub>	Forward rms current		11	Α
	Average forward	DPAK, $T_c = 110 ^{\circ}\text{C}$ , $\delta = 0.5$	4	А
'F(AV)	I <sub>F(AV)</sub> current	TO-220AC, $T_c = 95$ °C, $\delta = 0.5$	4	A
I <sub>FSM</sub>	Surge non repetitive forward current $ \begin{aligned} t_p &= 10 \text{ ms sinusoidal, } T_c = 25 \text{ °C} \\ t_p &= 10 \text{ ms sinusoidal, } T_c = 125 \text{ °C} \\ t_p &= 10 \text{ µs square, } T_c = 25 \text{ °C} \end{aligned} $		14 10 40	А
I <sub>FRM</sub>	Repetitive peak forward current DPAK, $T_c = 115 ^{\circ}\text{C}$ , $T_j = 150 ^{\circ}\text{C}$ , $\delta = 0.1$ TO-220AC, $T_c = 105 ^{\circ}\text{C}$ , $T_j = 150 ^{\circ}\text{C}$ , $\delta = 0.1$		14	А
T <sub>stg</sub>	Storage temperature range		-55 to +175	°C
Tj	Operating junction temperature <sup>(1)</sup>		-40 to +175	°C

<sup>1.</sup>  $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter		Value	Unit
D	P. Junction to coop		5.5	°C/W
R <sub>th(j-c)</sub> Junction to case	DPAK	4.5	C/VV	

Table 4. Static electrical characteristics

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage	T <sub>j</sub> = 25 °C	\/- <b>-</b> \/	-	10	50	μA
'R	current	T <sub>j</sub> = 150 °C	$V_R = V_{RRM}$	-	60	500	μΑ
V <sub>F</sub> <sup>(2)</sup>	Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 4 A	-	1.55	1.9	V
VF (-)	Forward voltage drop	T <sub>j</sub> = 150 °C	IF = 4 A	-	1.9	2.4	

<sup>1.</sup>  $t_p = 10 \text{ ms}, \delta < 2\%$ 

To evaluate the conduction losses use the following equation:

$$P = 1.20x I_{F(AV)} + 0.3 x I_{F^2(RMS)}$$



<sup>2.</sup>  $t_p = 500 \ \mu s, \ \delta < 2\%$ 

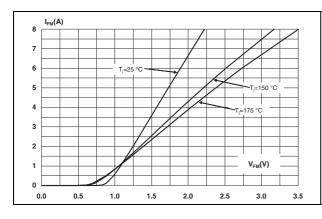
STPSC406 Characteristics

Table 5. Other parameters

Symbol	Parameter	Test conditions	Тур.	Unit
Q <sub>c</sub>	Total capacitive charge	$V_r = 400 \text{ V}, I_F = 4 \text{ A } dI_F/dt = -200 \text{ A/}\mu\text{s}$ $T_j = 150 \text{ °C}$	3	nC
С	Total capacitance	$V_r = 0 \text{ V}, T_C = 25 \text{ °C}, F = 1 \text{ Mhz}$	200	pF
		$V_r = 400 \text{ V}, T_c = 25 \text{ °C}, F = 1 \text{ Mhz}$	20	ρF

Figure 1. Forward voltage drop versus forward current (typical values)

Figure 2. Reverse leakage current versus reverse voltage applied (maximum values)



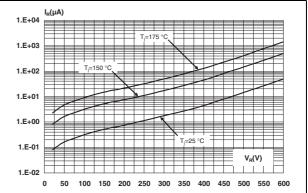
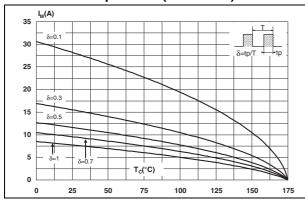
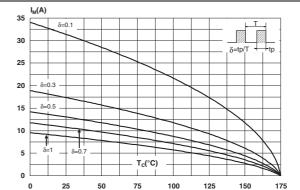


Figure 3. Peak forward current versus case temperature (TO-220AC)

Figure 4. Peak forward current versus case temperature (DPAK)





Characteristics STPSC406

Figure 5. Junction capacitance versus reverse voltage applied (typical values)

C(pF)

150

125

100

75

50

V<sub>R</sub>(V)

Figure 6. Relative variation of thermal impedance junction to case versus pulse duration (TO-220AC)

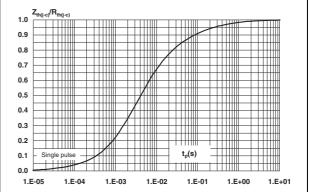


Figure 7. Relative variation of thermal impedance junction to case versus pulse duration (DPAK)

1.0 0.9 0.8 0.7 0.6 0.5 0.4 0.3 0.2 0.1 1.E-05 1.E-04 1.E-03 1.E-02 1.E+00 1.E+01

Figure 8. Non-repetitive peak surge forward current versus pulse duration (sinusoidal waveform)

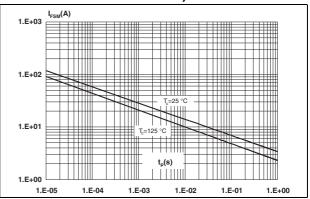
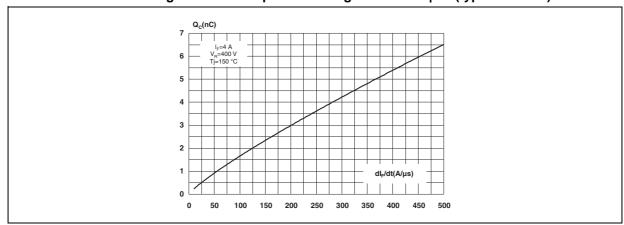


Figure 9. Total capacitive charges versus dl<sub>F</sub>/dt (typical values)



4/8 DocID16283 Rev 2

## 2 Package information

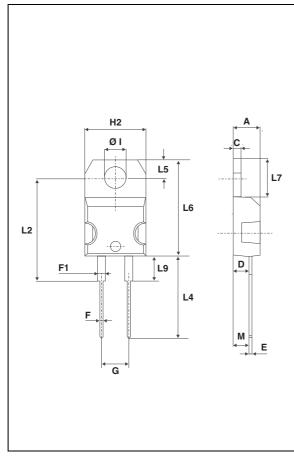
• Epoxy meets UL94, V0

• Cooling method: convection (C)

• Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

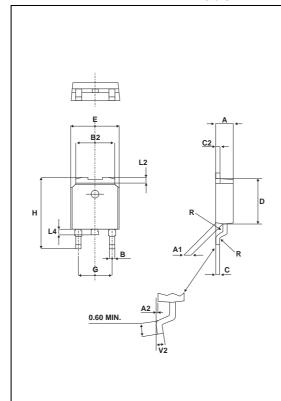
Table 6. TO-220AC dimensions



	Dimensions					
Ref.	Millim	neters	Inc	hes		
	Min. Max.		Min.	Max.		
Α	4.40	4.60	0.173	0.181		
С	1.23	1.32	0.048	0.051		
D	2.40	2.72	0.094	0.107		
E	0.49	0.70	0.019	0.027		
F	0.61	0.88	0.024	0.034		
F1	1.14	1.70	0.044	0.066		
G	4.95	5.15	0.194	0.202		
H2	10.00	10.40	0.393 0.409			
L2	16.40	) typ.	0.645 typ.			
L4	13.00	14.00	0.511	0.551		
L5	2.65	2.95	0.104	0.116		
L6	15.25	15.75	0.600	0.620		
L7	6.20	6.60	0.244	0.259		
L9	3.50	3.93	0.137	0.154		
М	2.6	typ.	0.102	2 typ.		
Diam. I	3.75	3.85	0.147	0.151		

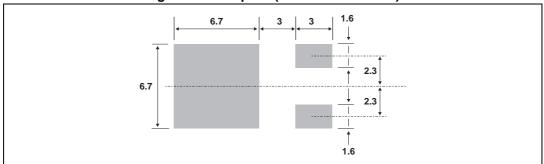
Package information STPSC406

Table 7. DPAK dimensions



	Dimensions				
Ref.	Millin	neters	Inc	hes	
	Min.	Max.	Min.	Max.	
Α	2.20	2.40	0.086	0.094	
A1	0.90	1.10	0.035	0.043	
A2	0.03	0.23	0.001	0.009	
В	0.64	0.90	0.025	0.035	
B2	5.20	5.40	0.204	0.212	
С	0.45	0.60	0.017	0.023	
C2	0.48	0.60	0.018	0.023	
D	6.00	6.20	0.236	0.244	
Е	6.40	6.60	0.251	0.259	
G	4.40	4.60	0.173	0.181	
Н	9.35	10.10	0.368	0.397	
L2	0.80 typ.		0.03	1 typ.	
L4	0.60	1.00	0.023	0.039	
V2	0°	8°	0°	8°	

Figure 10. Footprint (dimensions in mm)



# 3 Ordering information

**Table 8. Ordering information** 

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPSC406D	STPSC406D	TO-220AC	1.86 g	50	Tube
STPSC406B-TR	STPSC 406B	DPAK	0.3g	2500	Tape and reel

# 4 Revision history

Table 9. Document revision history

Date	Revision	Changes
24-Sep-2009	1	First issue.
12-Aug-2015	2	Updated Table 8: Ordering information.

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